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# HA16654A, HA16664A Series

## PWM Controlled Switching Regulator

# HITACHI

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The HA16654A and HA16664A are PWM control switching regulator ICs which drive a power MOSFET at high speed and high frequency. The standby current is limited to as small as 1.5 mA (typ). These devices incorporate totem pole circuits suited for high-speed push-pull operation at the output stage, accomplishing high-speed switching with rising time  $t_r = 80$  ns (typ) and falling time  $t_f = 40$  ns (typ) at 20 V swing.

### Functions

- Reference voltage circuit
- Triangular waveform oscillation circuit
- PWM comparator circuit
- Low-input malfunction protection circuit
- Output drive circuit
- Soft start and quick shut down

### Features

- High speed switching:  $t_r = 80$  ns,  $t_f = 40$  ns (typ) when use external driver circuit
- High frequency operation:  
HA16654A ( $f = 100$  kHz to 500 kHz)  
HA16664A ( $f = 100$  kHz to 200 kHz)  
Low power dissipation : 2 mA max in standby state
- 5 V reference voltage
- Low-input malfunction protection (High threshold voltage: 10 V Typ, Low threshold voltage: 8 V Typ)
- Adjustable dead band width
- Enlarged output pulse width control range (0 to 80%)
- Soft start and quick shut down functions
- Single output: totem pole

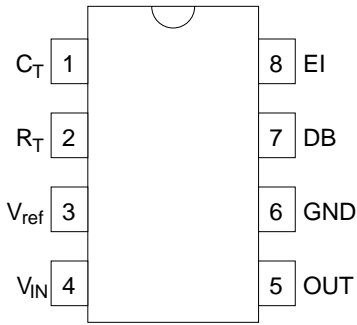
# HA16654A, HA16664A Series

## Ordering Information

| Type No.   | Operating Frequency | Package |
|------------|---------------------|---------|
| HA16654APS | 100 kHz to 500 kHz  | DP-8    |
| HA16654AFP |                     | FP-14DA |
| HA16664APS | 100 kHz to 200 kHz  | DP-8    |
| HA16664AFP |                     | FP-14DA |

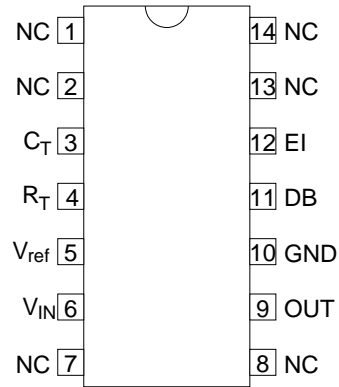
## Pin Arrangement

- HA16654APS, HA16664APS



(Top view)

- HA16654AFP, HA16664AFP



(Top view)

**Table 1 Pin Function**

| Symbol    | Pin Name          |
|-----------|-------------------|
| $C_T$     | Timing capacitor  |
| $R_T$     | Timing resistor   |
| $V_{ref}$ | Reference voltage |
| $V_{IN}$  | Input voltage     |
| EI        | Error input       |
| DB        | Dead band         |
| GND       | Ground            |
| OUT       | Driver output     |

Block Diagram

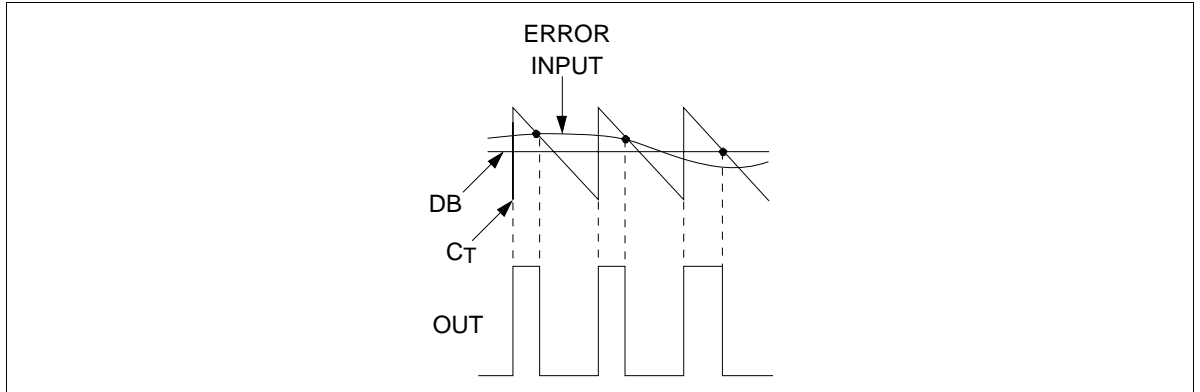
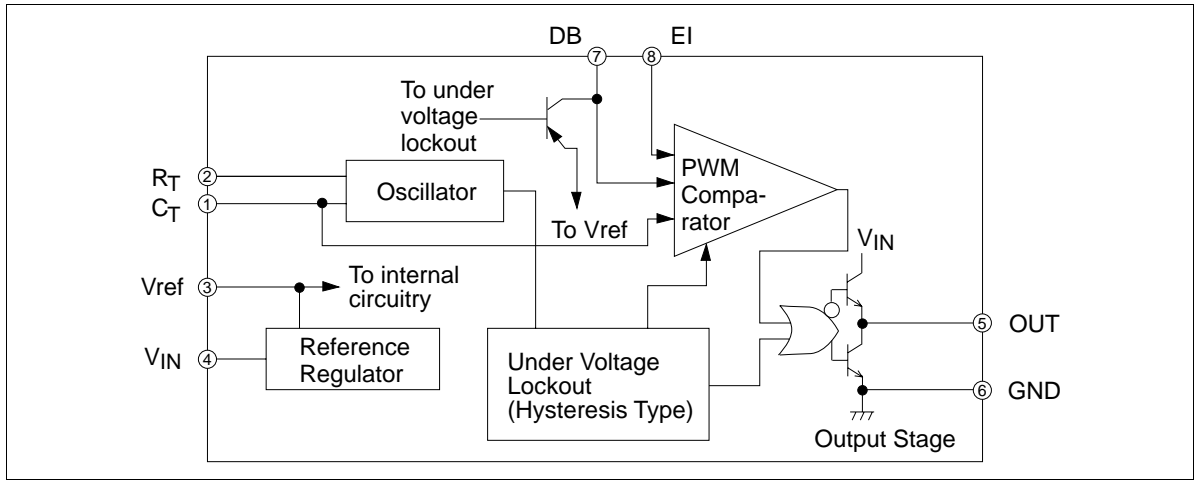


Figure 1 Waveform Timing

# HA16654A, HA16664A Series

## Absolute Maximum Ratings (Ta = 25°C)

| Item                          | Symbol           | Rating                 | Unit | Notes |
|-------------------------------|------------------|------------------------|------|-------|
| Power supply voltage          | V <sub>IN</sub>  | +40                    | V    |       |
| Collector current (Push-pull) | I <sub>O</sub>   | 20                     | mA   |       |
| Comparator input voltage      | V <sub>COM</sub> | V <sub>ref</sub> + 0.3 | V    |       |
| R <sub>T</sub> input current  | I <sub>RT</sub>  | 1                      | mA   |       |
| Power dissipation             | P <sub>T</sub>   | 680                    | mW   | 1, 2  |
| Operation temperature range   | Topr             | -20 to +85             | °C   |       |
| Storage temperature range     | Tstg             | -55 to 125             | °C   |       |

Notes: 1. Ta ≤ 45°C, if Ta > 45°C, derate by 8.3 mW/°C

2. Tjmax = θj-a • Pcmx + Ta (θj-a: Thermal resistance between junction and atmosphere at set board use)

The wiring density and the material of the set board must be chosen for thermal conductance of efficacy board.

## Electrical Characteristics

HA16654APS/AFP (Ta = 25°C, V<sub>IN</sub> = 20 V, C<sub>T</sub> = 220 pF, R<sub>T</sub> = 27 kΩ at f = 500 kHz)

### Voltage Reference

| Item                  | Symbol           | Min  | Typ  | Max  | Unit   | Test Condition                |
|-----------------------|------------------|------|------|------|--------|-------------------------------|
| Output voltage        | V <sub>ref</sub> | 4.75 | 5.00 | 5.25 | V      |                               |
| Line regulation       | Line             | —    | —    | 100  | mV     | V <sub>IN</sub> = 7.3 to 11 V |
|                       |                  | —    | 10   | 25   | mV     | V <sub>IN</sub> = 11 to 40 V  |
| Load regulation       | Load             | —    | 5    | 16   | mV     | I <sub>O</sub> = 0 to 10 mA   |
| Temperature stability | V <sub>RTC</sub> | —    | -26  | —    | ppm/°C |                               |
| Short circuit current | I <sub>OS</sub>  | 10   | 35   | —    | mA     | V <sub>ref</sub> = 0 V        |

## Oscillator

| Item              | Symbol    | Min | Typ   | Max       | Unit  | Test Condition                         |
|-------------------|-----------|-----|-------|-----------|-------|--|
| Maximum frequency | $f_{max}$ | 500 | —     | —         | kHz   | $C_T = 220 \text{ pF}$                 |
| Minimum frequency | $f_{min}$ | —   | —     | 100       | kHz   | $C_T = 560 \text{ pF}$                 |
| Initial accuracy  | $f_{dev}$ | —   | —     | $\pm 10$  | %     |  |
| Voltage stability | $f_{av}$  | —   | -0.02 | $\pm 1.0$ | kHz/V | $V_{IN} = 11 \text{ to } 40 \text{ V}$ |

## PWM

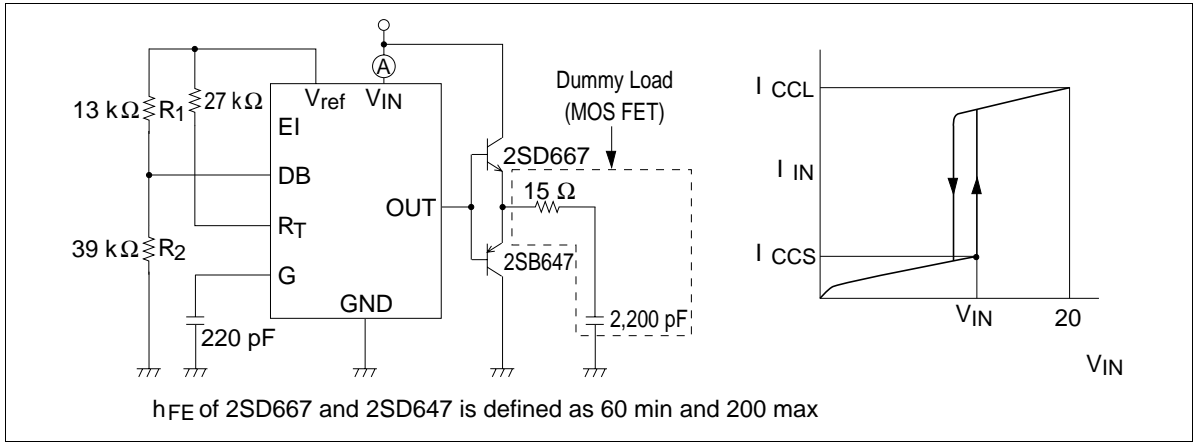
| Item                | Symbol | Min | Typ     | Max     | Unit          | Test Condition  |
|---------------------|--------|-----|---------|---------|---------------|---|
| Maximum duty cycle  | Du     | 80  | —       | —       | %             |   |
| Duty cycle accuracy | Ddev   | —   | $\pm 1$ | $\pm 6$ | %             | $R_1 = 13 \text{ k}\Omega, R_2 = 39 \text{ k}\Omega$  |
| Input bias current  | $I_B$  | —   | —       | 2.0     | $\mu\text{A}$ | $V_{E1} = 4 \text{ V}, V_{DB} = 0 \text{ V}$ or<br>$V_{E1} = 0 \text{ V}, V_{DB} = 4 \text{ V}$ |

## Output Driver

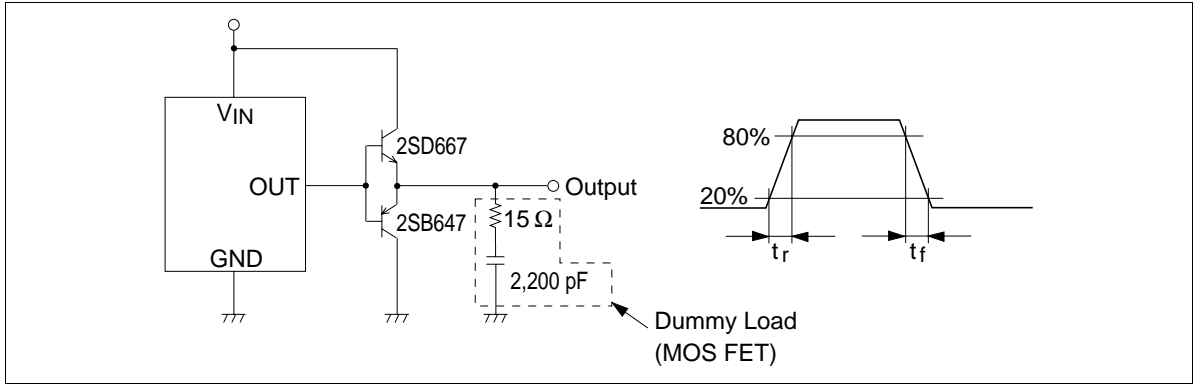
| Item                         | Symbol        | Min            | Typ  | Max | Unit | Test Condition                                  |
|------------------------------|---------------|----------------|------|-----|------|---|
| Sink current at $V_{in}$ low | $I_{OS(Low)}$ | 0.6            | 1.5  | —   | mA   | $V_{IN} = 6 \text{ V}, V_{OUT} = 0.4 \text{ V}$ |
| Output low level             | $V_{OL}$      | —              | 0.86 | 1.4 | V    | $I_O(\text{sink}) = 10 \text{ mA}$              |
| Output high level            | $V_{OH}$      | $V_{IN} - 2.2$ | —    | —   | V    | $I_O(\text{source}) = 10 \text{ mA}$            |
| Output rising time           | $t_r$         | —              | 80   | 150 | ns   | Figure 3  |
| Output falling time          | $t_f$         | —              | 40   | 100 | ns   | Figure 3  |
| High level threshold         | $V_{THH}$     | 9              | 10   | 11  | V    | UVL characteristics                             |
| Low level threshold          | $V_{THL}$     | 7.3            | 8    | 9   | V    | UVL characteristics                             |
| Hysteresis width             | $V_{HRS}$     | 1.5            | 2.0  | 2.5 | V    | UVL characteristics                             |

## Total Current

| Item              | Symbol    | Min | Typ | Max  | Unit | Test Condition   |
|-------------------|-----------|-----|-----|------|------|--|
| Standby current   | $I_{CCS}$ | —   | 1.5 | 2.0  | mA   | Figure 2   |
| Operation current | $V_{CCL}$ | 5.0 | 9.0 | 13.0 | mA   | $R_1 = 13 \text{ k}\Omega, R_2 = 29 \text{ k}\Omega,$<br>$V_{IN} = 20 \text{ V}$<br>Figure 2 |



**Figure 2**  $I_{CCS} \cdot I_{CCL}$  Measurement Circuit



**Figure 3**  $t_r, t_f$  Measurement Circuit

HA16664APS/AFP ( $T_a = 25^\circ\text{C}$ ,  $V_{IN} = 20\text{ V}$ ,  $C_T = 560\text{ pF}$ ,  $R_T = 82\text{ k}\Omega$  at  $f = 100\text{ kHz}$ )

## Voltage Reference

| Item                  | Symbol    | Min  | Typ  | Max  | Unit                  | Test Condition                       |
|-----------------------|-----------|------|------|------|-----------------------|--------------------------------------|
| Output voltage        | Vref      | 4.75 | 5.00 | 5.25 | V                     |                                      |
| Line regulation       | Line      | —    | —    | 100  | mV                    | $V_{IN} = 7.3\text{ to }11\text{ V}$ |
|                       |           | —    | 10   | 25   | mV                    | $V_{IN} = 11\text{ to }40\text{ V}$  |
| Load regulation       | Load      | —    | 5    | 16   | mV                    | $I_O = 0\text{ to }10\text{ mA}$     |
| Temperature stability | $V_{RTC}$ | —    | -26  | —    | ppm/ $^\circ\text{C}$ |                                      |
| Short circuit current | $I_{OS}$  | 10   | 35   | —    | mA                    | Vref = 0 V                           |

**Oscillator**

| Item              | Symbol           | Min | Typ   | Max       | Unit  | Test Condition                                |
|-------------------|------------------|-----|-------|-----------|-------|---|
| Maximum frequency | $f_{\max}$       | 200 | —     | —         | kHz   | $C_T = 220 \text{ pF}$                        |
| Minimum frequency | $f_{\min}$       | —   | —     | 100       | kHz   | $C_T = 560 \text{ pF}$                        |
| Initial accuracy  | $f_{\text{dev}}$ | —   | —     | $\pm 10$  | %     |   |
| Voltage stability | $f_{\text{av}}$  | —   | -0.02 | $\pm 1.0$ | kHz/V | $V_{\text{IN}} = 11 \text{ to } 40 \text{ V}$ |

**PWM Comparator**

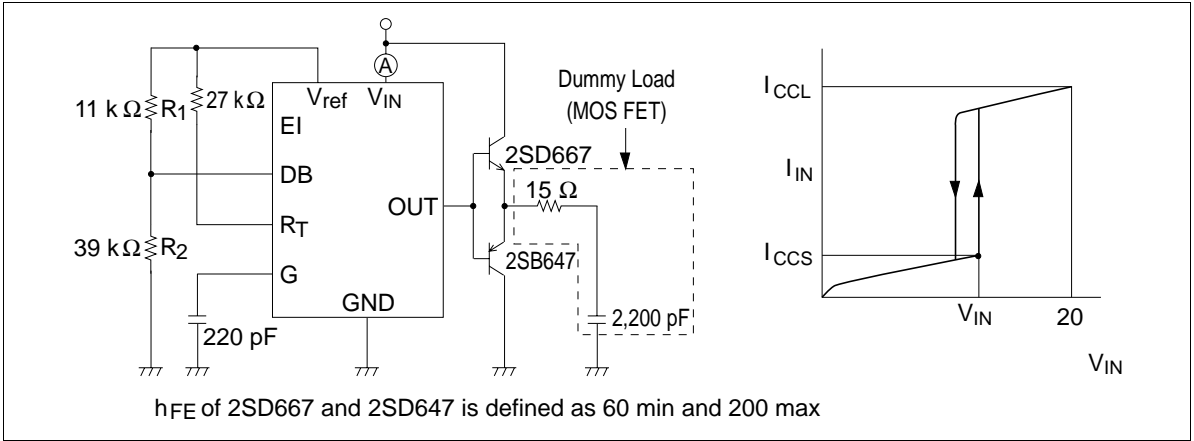
| Item                | Symbol | Min | Typ       | Max     | Unit          | Test Condition  |
|---------------------|--------|-----|-----------|---------|---------------|---|
| Maximum duty cycle  | Du     | 80  | —         | —       | %             |   |
| Duty cycle accuracy | Ddev   | —   | $\pm 1.0$ | $\pm 6$ | %             | $R_1 = 11 \text{ k}\Omega, R_2 = 39 \text{ k}\Omega$  |
| Input bias current  | $I_B$  | —   | —         | 2.0     | $\mu\text{A}$ | $V_{\text{EI}} = 4 \text{ V}, V_{\text{DB}} = 0 \text{ V}$ or<br>$V_{\text{EI}} = 0 \text{ V}, V_{\text{DB}} = 4 \text{ V}$ |

**Output Driver**

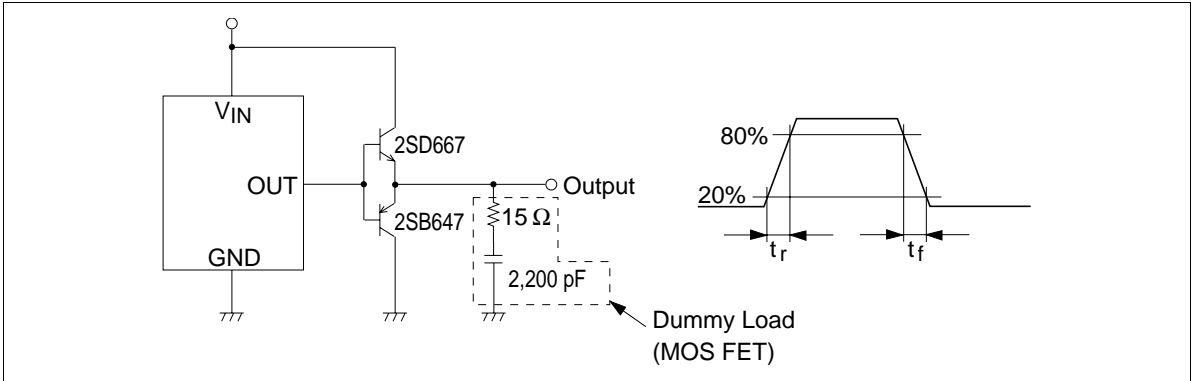
| Item                    | Symbol               | Min                   | Typ  | Max | Unit | Test Condition  |
|-------------------------|----------------------|-----------------------|------|-----|------|---|
| Sink current at Vin low | $I_{\text{OS(Low)}}$ | 1.0                   | 1.5  | —   | mA   | $V_{\text{IN}} = 6 \text{ V}, V_{\text{OUT}} = 0.4 \text{ V}$ |
| Output low level        | $V_{\text{OL}}$      | —                     | 0.86 | 1.4 | V    | $I_{\text{O(sink)}} = 10 \text{ mA}$                          |
| Output high level       | $V_{\text{OH}}$      | $V_{\text{IN}} - 2.2$ | —    | —   | V    | $I_{\text{O(source)}} = 10 \text{ mA}$                        |
| Output rising time      | $t_r$                | —                     | 80   | 300 | ns   | Figure 5  |
| Output falling time     | $t_f$                | —                     | 40   | 200 | ns   | Figure 5  |
| High level threshold    | $V_{\text{THH}}$     | 9                     | 10   | 11  | V    | UVL characteristics   |
| Low level threshold     | $V_{\text{THL}}$     | 7.3                   | 8    | 9   | V    | UVL characteristics   |
| Hysteresis width        | $V_{\text{HRS}}$     | 1.5                   | 2.0  | 2.5 | V    | UVL characteristics   |

**Total Current**

| Item              | Symbol           | Min | Typ | Max | Unit | Test Condition  |
|-------------------|------------------|-----|-----|-----|------|---|
| Standby current   | $I_{\text{CCS}}$ | —   | 1.5 | 2.0 | mA   | Figure 4  |
| Operation current | $V_{\text{CCL}}$ | 3.0 | 5.0 | 7.0 | mA   | $R_1 = 11 \text{ k}\Omega, R_2 = 39 \text{ k}\Omega,$<br>$V_{\text{IN}} = 20 \text{ V}$<br>Figure 4 |

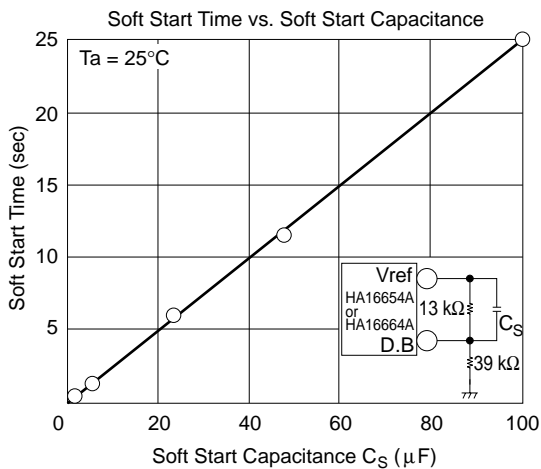
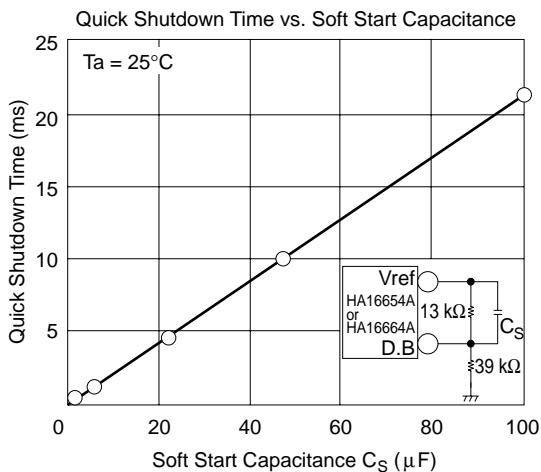
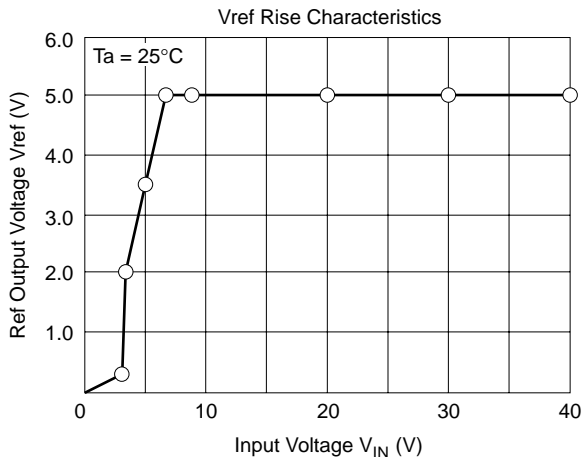
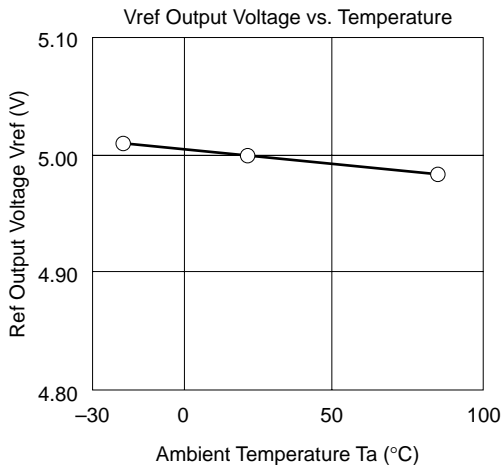


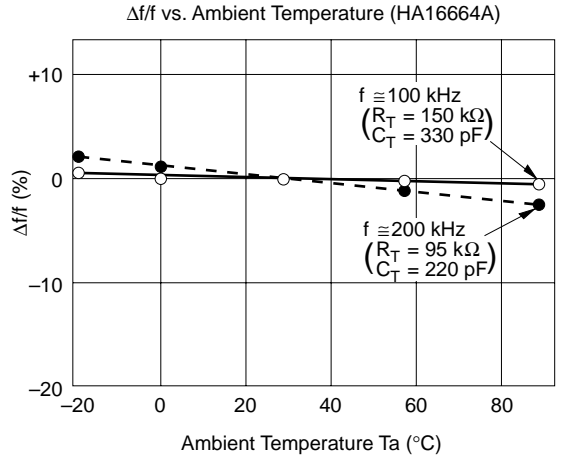
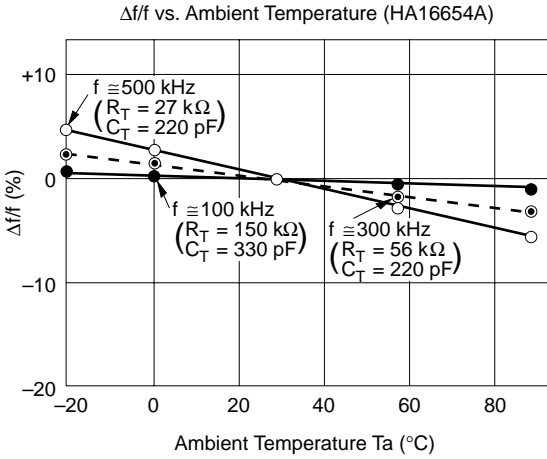
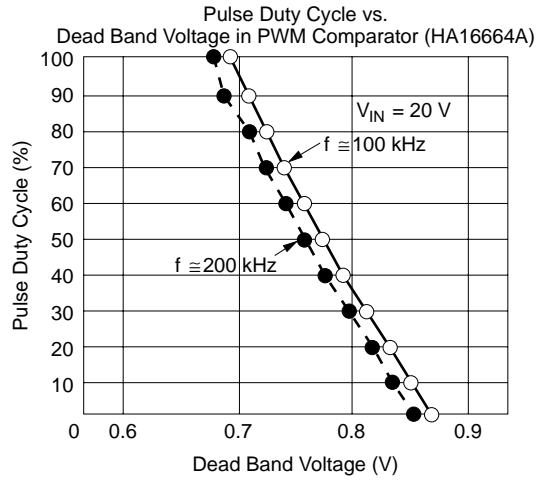
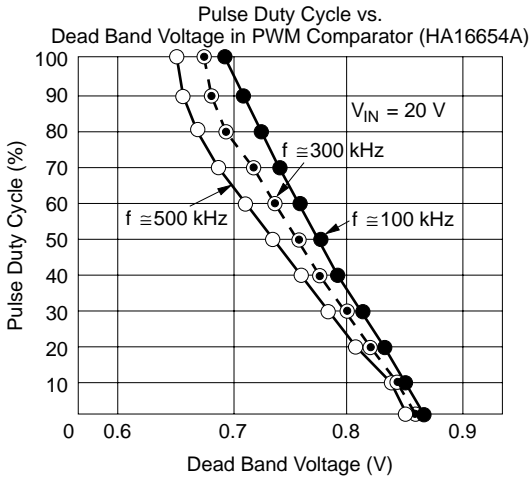
**Figure 4**  $I_{CCS} \cdot I_{CCL}$  Measurement Circuit



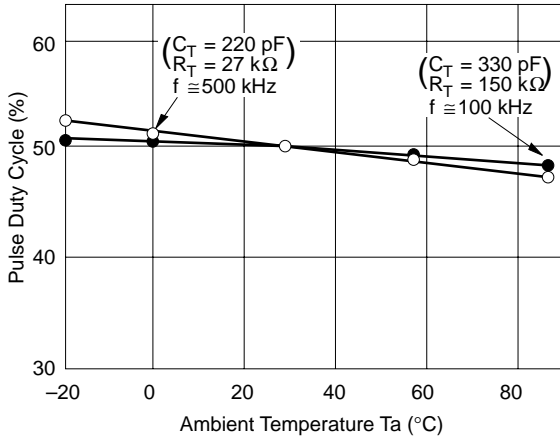
**Figure 5**  $t_r \cdot t_f$  Measurement Circuit

## Characteristic Curves

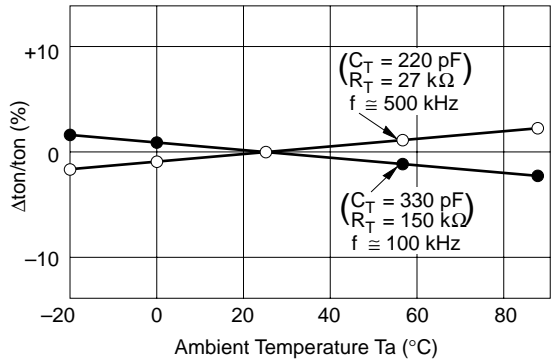




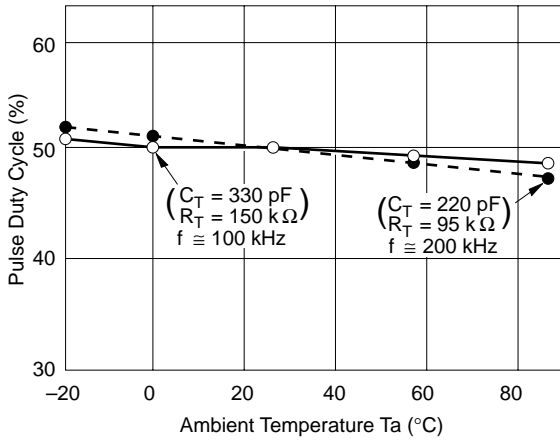
Pulse Duty Cycle vs. Ambient Temperature (HA16654A)



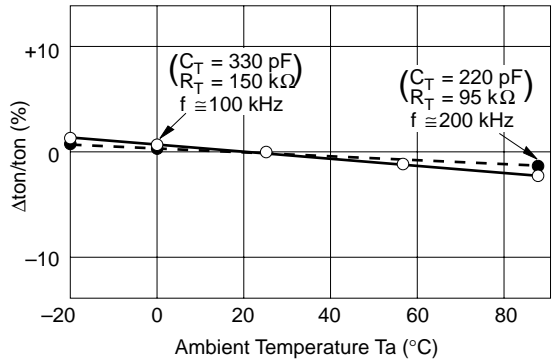
$\Delta$ ton/ton vs. Ambient Temperature (HA16654A)



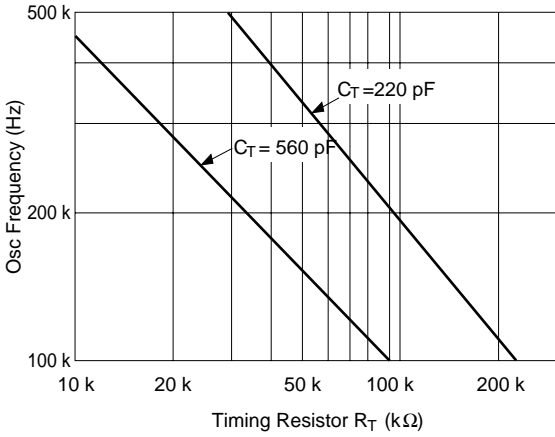
Pulse Duty Cycle vs. Ambient Temperature (HA16664A)



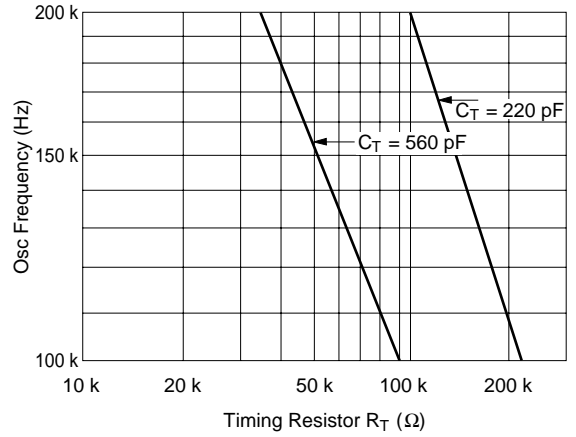
$\Delta$ ton/ton vs. Ambient Temperature (HA16664A)



OSC Frequency vs. Timing Resistor (HA16654A)



OSC Frequency vs. Timing Resistor (HA16664A)



Formula for the oscillation frequency  $f$

$$f = 1 / [ \{ C_T (R_T + 1 \times 10^3)(a \cdot R_T + b) / (V_{ref} - V_{BE}) \} + 100 \times 10^{-9} ]$$

$C_T$  : Timing capacitor (F)

$R_T$  : Timing resistor ( $\Omega$ )

$V_{ref}$  : Reference voltage 5.0 (V) (Typ)

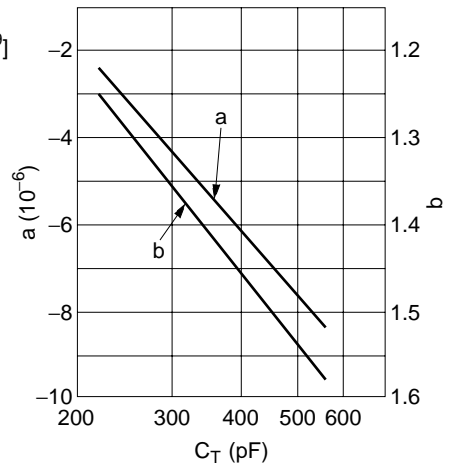
$V_{BE}$  : Base-emitter voltage 0.65 (V) (Typ)

The following table show empirical values of  $a$  and  $b$  for different values of  $C_T$ .

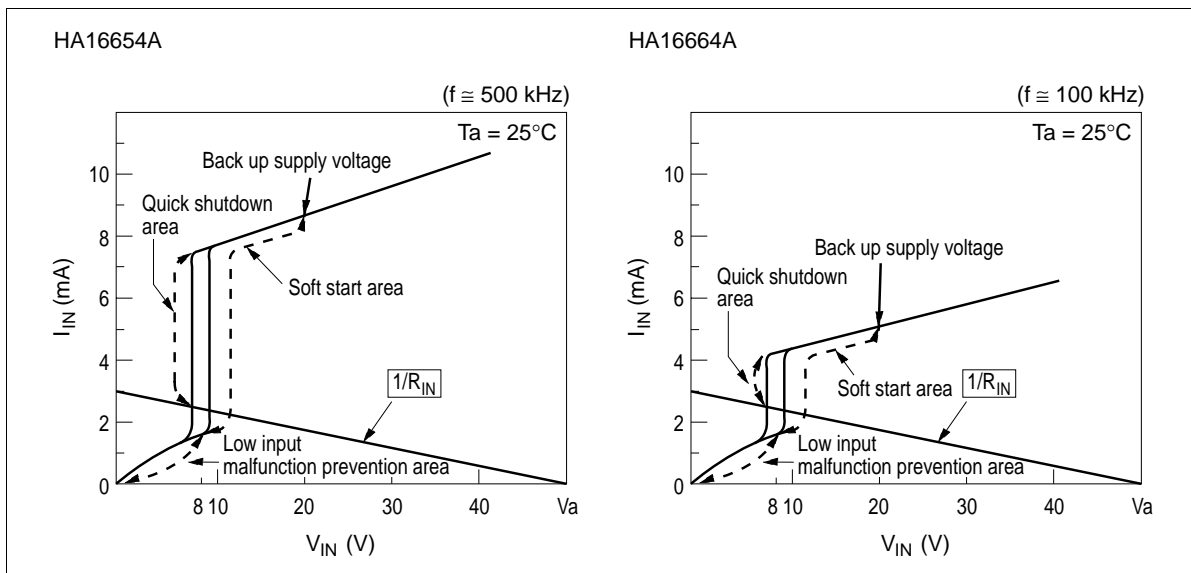
| $C_T$ (pF) | $a$                    | $b$   |
|------------|------------------------|-------|
| 220        | $-2.30 \times 10^{-6}$ | 1.247 |
| 560        | $-8.37 \times 10^{-6}$ | 1.575 |

Also,

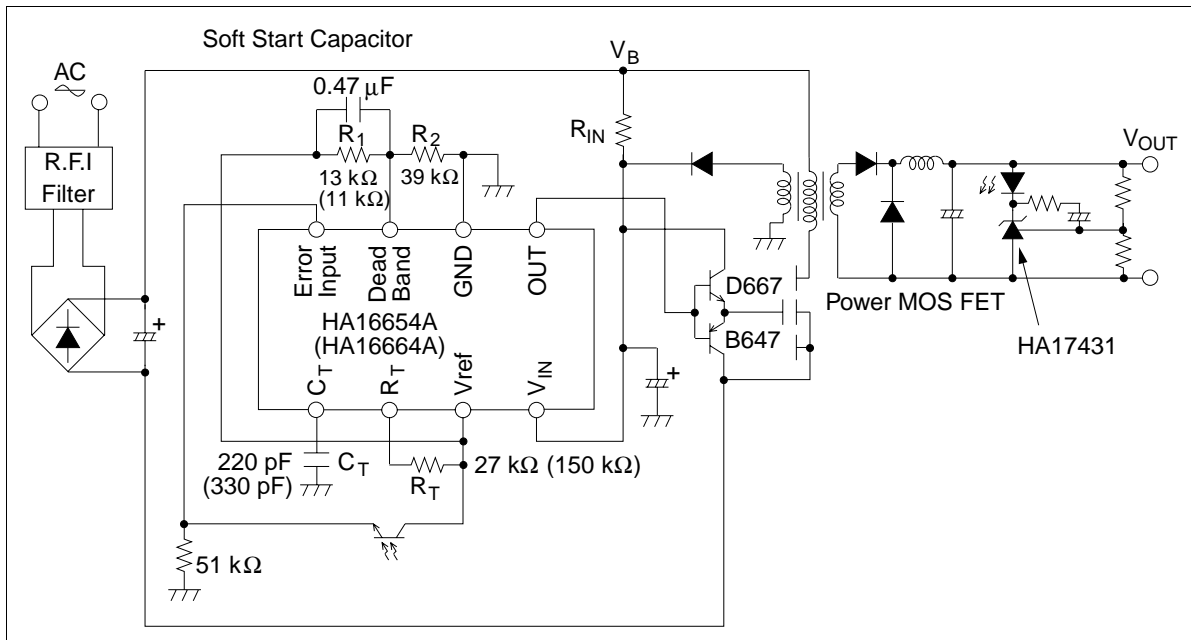
$$f \approx 4.35 / (C_T \cdot R_T)$$



$V_{IN}$  Bias Point

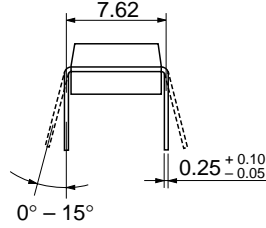
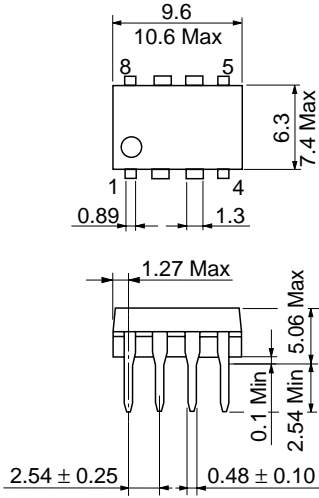


Primary Control Forward Converter System



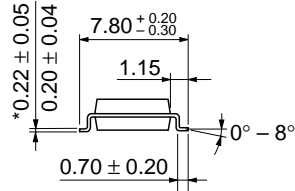
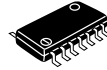
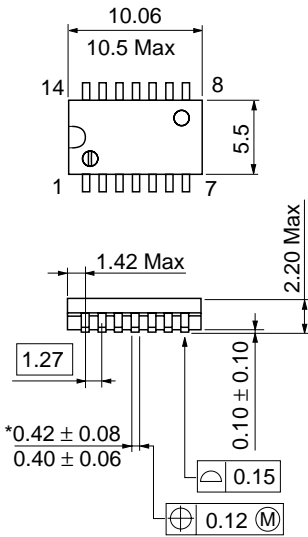
## Package Dimensions

Unit: mm



|                        |          |
|------------------------|----------|
| Hitachi Code           | DP-8     |
| JEDEC                  | Conforms |
| EIAJ                   | Conforms |
| Mass (reference value) | 0.54 g   |

Unit: mm



|                        |          |
|------------------------|----------|
| Hitachi Code           | FP-14DA  |
| JEDEC                  | —        |
| EIAJ                   | Conforms |
| Mass (reference value) | 0.23 g   |

\*Dimension including the plating thickness  
Base material dimension

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